imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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Features and Benefits

- Integrated on-time control circuit (it realizes high power factor by average current control)
- Integrated startup circuit (no external startup circuit necessary)
- Integrated soft-start circuit (reduces power stress during start-up on the incorporated power MOSFET and output rectifier)
- Integrated bias assist circuit (improves startup performance, suppresses VCC voltage droop during operation, and allows use of low-rated ceramic capacitor on VCC pin)
- Integrated Leading Edge Blanking (LEB) circuit
- Integrated maximum on-time limit circuit
- Protection features:
- Overcurrent protection (OCP): pulse-by-pulse
- Overvoltage protection (OVP): pins VCC, OVP, and OCP, auto restart
- Overload protection (OLP): auto restart
- Thermal shutdown (TSD): latched shutdown

Package: 7-pin TO-220F



Description

The LC5500 series is the power IC for the LED driver which has an incorporated power MOSFET, designed for input capacitorless applications, and making it possible for systems to comply with the harmonics standard (IEC61000-3-2 class C). The controller adapts the average current control method for realizing high power factors, and the quasi-resonant topology contributes to high efficiency and low EMI noise.

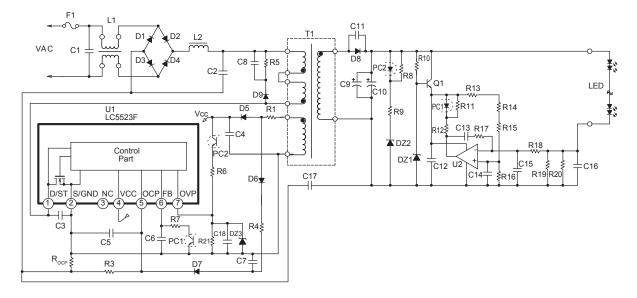
The rich set of protection features helps to realize low component counts, and high performance-to-cost power supply.

The LC5523F is intended for isolated designs. The incorporated MOSFET has a $V_{DSS}(min)$ rating of 650 V and $R_{DS(on)}(max)$ of 1.9 Ω . It is capable of a maximum output power of 60 W on 230 VAC supply and 40 W on universal input supply (85 to 265VAC) based on the thermal rating. Note that the maximum output power can be up to 120% to 140% of this value. However, it may be limited in applications with low output voltage or short duty cycle.

Applications

- LED lighting fixtures
- LED light bulbs

Typical Application



Selection Guide

Part Number Package	
LC5523F	TO-220F (specify leadform when ordering)

The polarity value for current specifies a sink as "+," and a source as "-," referencing the IC.

Absolute Maximum Ratings T_A = 25°C, unless otherwise specified

Characteristic	Symbol	Notes	Pins	Rating	Unit
Drain Current ¹	I _{DPeak}	Single pulse	1 – 2	9.2	A
Single Pulse Avalanche Energy ²	E _{AS}	I_{LPeak} = 2.9 A, V_{DD} = 99 V, L = 20 mH	1 – 2	99	mJ
Control Part Input Voltage	V _{CC}		4 – 2	35	V
OCP Pin Voltage	V _{OCP}		5 – 2	-2.0 to 5.0	V
FB Pin Voltage	V _{FB}		6 – 2	-0.3 to 7.0	V
OVP Pin Voltage	V _{OVP}		7 – 2	-0.3 to 5.0	V
Allowable Power Dissipation of	With infinite heatsink	1 – 2	20.2	W	
MOSFET ³		Without heatsink	1 – 2	1.8	W
Internal Frame Temperature in Operation	T _F		_	-20 to 115	°C
Operating Ambient Temperature	T _{OP}		—	-55 to 115	°C
Storage Temperature	T _{stg}		—	-55 to 125	°C
Channel Temperature	T _{ch}		_	150	°C

¹Refer to MOSFET Safe Operating Area Curve.

²Refer to MOSFET Avalanche Energy Derating Coefficient Curve.

³Refer to MOSFET Temperature versus Power Dissipation Curve.

LC5523F

Single-Stage Power Factor Corrected Off-Line Switching Regulator IC

ELECTRICAL CHARACTERISTICS of Control Part T_A = 25°C, V_{CC} = 20 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Pins	Min.	Тур.	Max.	Unit
Startup Operation	4						
Operation Start Voltage	V _{CC(ON)}		4 – 2	13.8	15.1	17.3	V
Operation Stop Voltage*	V _{CC(OFF)}		4 – 2	8.4	9.4	10.7	V
Operating Current	I _{CC(ON)}		4 – 2	-	-	3.7	mA
Startup Circuit Operation Voltage	VSTARTUP		1 – 2	42	57	72	V
Startup Current	I _{CC(STARTUP)}	V _{CC} = 13 V	4 – 2	-5.5	-3.0	-1.0	mA
Startup Current Threshold Biasing Voltage-1*	V _{CC(BIAS)1}		4 – 2	9.5	11.0	12.5	V
Startup Current Threshold Biasing Voltage-2	V _{CC(BIAS)2}		4 – 2	14.4	16.6	18.8	V
Normal Operation				•			
PWM Operation Frequency	fosc		1 – 2	11.0	14.0	18.0	kHz
Maximum On-Time	t _{ON(MAX)}		1 – 2	30.0	40.0	50.0	μs
FB Pin Voltage Minimum Limit	V _{FB(MIN)}		6 – 2	0.55	0.90	1.25	V
Maximum Feedback Current	I _{FB(MAX)}		6 – 2	-40	-25	-10	μA
Leading Edge Blanking Time	t _{ON(LEB)}		5 – 2	-	500	-	ns
Quasi-Resonant Operation Threshold Voltage-1	V _{BD(TH1)}		5 – 2	0.14	0.24	0.34	V
Quasi-Resonant Operation Threshold Voltage-2	V _{BD(TH2)}		5 – 2	0.12	0.17	0.22	V
Protection Operation			·				
OCP Pin Overcurrent Protection (OCP) Threshold Voltage	V _{OCP}		5 – 2	-0.66	-0.60	-0.54	V
OCP Pin Source Current	I _{OCP}		5 – 2	-120	-40	-10	μA
OCP Pin Overvoltage Protection (OVP) Threshold Voltage	V _{BD(OVP)}		5 – 2	2.2	2.6	3.0	V
Overload Protection (OLP) Threshold Voltage-1	V _{FB(OLP)1}		6 – 2	5.0	5.5	6.0	V
Overload Protection (OLP) Threshold Voltage-2	V _{FB(OLP)2}		6 – 2	4.1	4.5	4.9	V
OVP Pin OVP Threshold Voltage	V _{OVP(OVP)}		7 – 2	1.6	2.0	2.4	V
VCC Pin OVP Threshold Voltage	V _{CC(OVP)}		4 – 2	28.5	31.5	34.0	V
Thermal Shutdown Activating Temperature	T _{J(TSD)}		-	135	-	_	°C

 $V_{CC(BIAS)1} > V_{CC(OFF)}$ always.

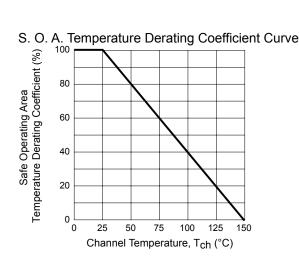
ELECTRICAL CHARACTERISTICS of MOSFET T_A = 25°C, unless otherwise specified

Characteristic	Symbol	Test Conditions	Pins	Min.	Тур.	Max.	Unit
Drain-to-Source Breakdown Voltage	V _{DSS}		1 – 2	650	—	—	V
Drain Leakage Current	I _{DSS}		1 – 2	_	_	300	μA
On Resistance	R _{DS(on)}		1 – 2	—	—	1.9	Ω
Switching Time	t _f		1 – 2	—	—	400	ns
Thermal Resistance	R _{θch-F}	Between channel and internal frame	—	_	_	3.1	°C/W

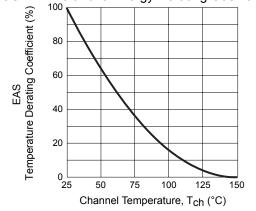
LC5523F

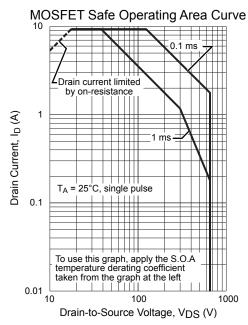
Single-Stage Power Factor Corrected Off-Line Switching Regulator IC

Characteristic Performance

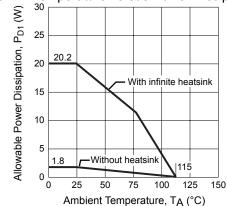


MOSFET Avalanche Energy Derating Coefficient Curve

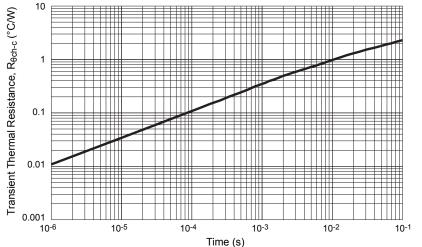




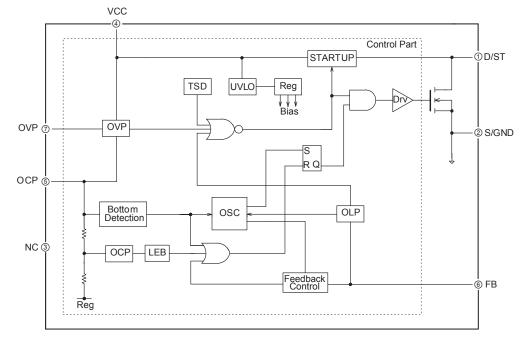
MOSFET Temperature versus Power Dissipation Curve



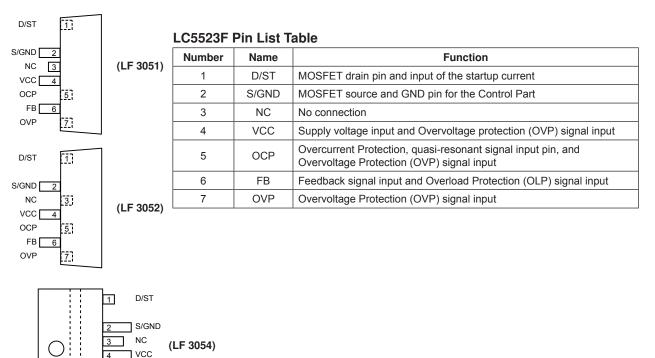




Functional Block Diagram

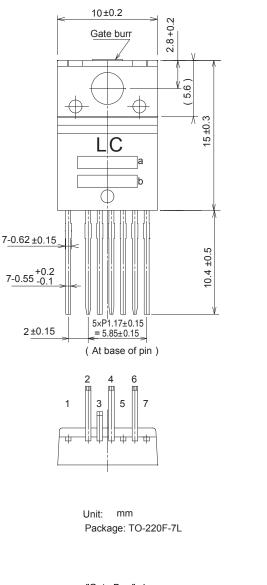


Pin-out Diagrams





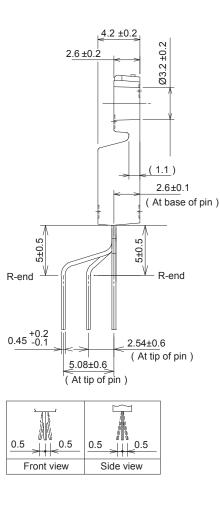
OCP



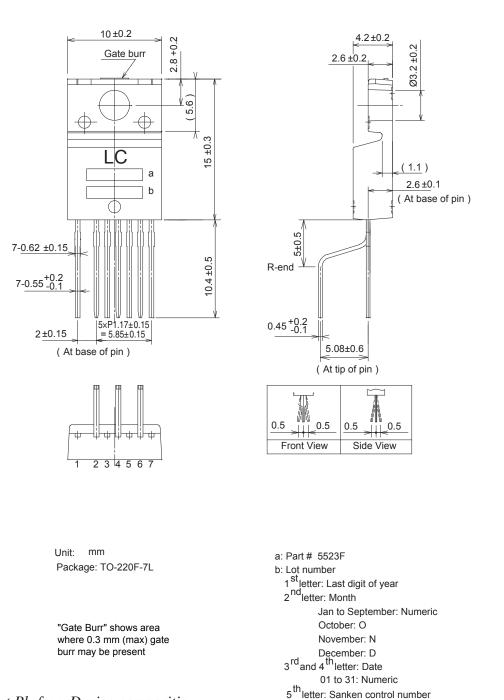
Package Outline Drawing, TO-220F Leadform 3051

"Gate Burr" shows area where 0.3 mm (max) gate burr may be present

Pin treatment Pb-free. Device composition compliant with the RoHS directive.

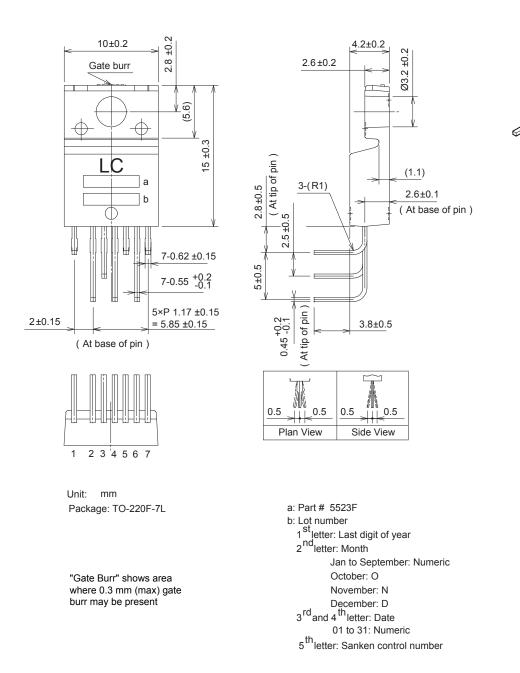


a: Part # 5523F b: Lot number 1stletter: Last digit of year 2ndletter: Month Jan to September: Numeric October: O November: N December: D 3rd and 4thletter: Date 01 to 31: Numeric 5thletter: Sanken control number



Package Outline Drawing, TO-220F Leadform 3052

Pin treatment Pb-free. Device composition compliant with the RoHS directive.



Package Outline Drawing, TO-220F Leadform 3054

Pin treatment Pb-free. Device composition compliant with the RoHS directive.

LC5523F

Single-Stage Power Factor Corrected Off-Line Switching Regulator IC

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

Cautions for Storage

- Ensure that storage conditions comply with the standard temperature (5°C to 35°C) and the standard relative humidity (around 40% to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of the products that have been stored for a long time.

Cautions for Testing and Handling

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between the product pins, and wrong connections. Ensure all test parameters are within the ratings specified by Sanken for the products.

Remarks About Using Silicone Grease with a Heatsink

- When silicone grease is used in mounting the products on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce excess stress.
- Volatile-type silicone greases may crack after long periods of time, resulting in reduced heat radiation effect. Silicone greases with low consistency (hard grease) may cause cracks in the mold resin when screwing the products to a heatsink.

Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

Туре	Suppliers
G746	Shin-Etsu Chemical Co., Ltd.
YG6260	Momentive Performance Materials Inc.
SC102	Dow Corning Toray Co., Ltd.

Cautions for Mounting to a Heatsink

• When the flatness around the screw hole is insufficient, such as when mounting the products to a heatsink that has an extruded (burred) screw hole, the products can be damaged, even with a lower than

recommended screw torque. For mounting the products, the mounting surface flatness should be 0.05 mm or less.

- Please select suitable screws for the product shape. Do not use a flat-head machine screw because of the stress to the products. Self-tapping screws are not recommended. When using self-tapping screws, the screw may enter the hole diagonally, not vertically, depending on the conditions of hole before threading or the work situation. That may stress the products and may cause failures.
- Recommended screw torque: 0.588 to 0.785 Nom (6 to 8 kgfocm).
- For tightening screws, if a tightening tool (such as a driver) hits the products, the package may crack, and internal stress fractures may occur, which shorten the lifetime of the electrical elements and can cause catastrophic failure. Tightening with an air driver makes a substantial impact. In addition, a screw torque higher than the set torque can be applied and the package may be damaged. Therefore, an electric driver is recommended.

When the package is tightened at two or more places, first pre-tighten with a lower torque at all places, then tighten with the specified torque. When using a power driver, torque control is mandatory.

Soldering

- When soldering the products, please be sure to minimize the working time, within the following limits:
 260±5°C 10±1 s (Flow, 2 times)
 380±10°C 3.5±0.5 s (Soldering iron, 1 time)
- Soldering should be at a distance of at least 2.0 mm from the body of the products.

Electrostatic Discharge

- When handling the products, the operator must be grounded. Grounded wrist straps worn should have at least 1 M Ω of resistance from the operator to ground to prevent shock hazard, and it should be placed near the operator.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in order to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in Sanken shipping containers or conductive containers, or be wrapped in aluminum foil.

- The contents in this document are subject to changes, for improvement and other purposes, without notice. Make sure that this is the latest revision of the document before use.
- Application and operation examples described in this document are quoted for the sole purpose of reference for the use of the products herein and Sanken can assume no responsibility for any infringement of industrial property rights, intellectual property rights or any other rights of Sanken or any third party which may result from its use.
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• In the case that you use Sanken products or design your products by using Sanken products, the reliability largely depends on the degree of derating to be made to the rated values. Derating may be interpreted as a case that an operation range is set by derating the load from each rated value or surge voltage or noise is considered for derating in order to assure or improve the reliability. In general, derating factors include electric stresses such as electric voltage, electric current, electric power etc., environmental stresses such as ambient temperature, humidity etc. and thermal stress caused due to self-heating of semiconductor products. For these stresses, instantaneous values, maximum values and minimum values must be taken into consideration.

In addition, it should be noted that since power devices or IC's including power devices have large self-heating value, the degree of derating of junction temperature affects the reliability significantly.

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